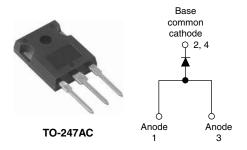




Vishay High Power Products

Fast Soft Recovery Rectifier Diode, 80 A



PRODUCT SUMMARY				
V _F at 40 A	< 1.2 V			
t _{rr}	90 ns			
V _{RRM}	1000/1200 V			

FEATURES/DESCRIPTION

The 80EPF..PbF fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.



RoHS*

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

This product series has been designed and qualified for industrial level and lead (Pb)-free.

APPLICATIONS

- Output rectification and freewheeling in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	TEST CONDITIONS	VALUES	UNITS			
V _{RRM}		1000/1200	V			
I _{F(AV)}	Sinusoidal waveform	80	Δ.			
I _{FSM}		1100	A			
t _{rr}	1 A, - 100 A/μs	90	ns			
V _F	40 A, T _J = 25 °C	1.2	V			
T _J		- 40 to 150	°C			

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA				
80EPF10PbF	1000	1100	12				
80EPF12PbF	1200	1300	12				

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	T _C = 92 °C, 180° conduction half sine wave	80			
Maximum peak one cycle	I _{FSM}	10 ms sine pulse, rated V _{RRM} applied	1100	Α		
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	1250			
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	A ² s			
waxiinum i-t ioi iusing	1-1	10 ms sine pulse, no voltage reapplied				
Maximum $I^2\sqrt{t}$ for fusing	I²√t	t = 0.1 to 10 ms, no voltage reapplied	70 000	A²√s		

^{*} Pb containing terminations are not RoHS compliant, exemptions may apply

80EPF..PbF Soft Recovery Series

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS			
Maximum forward voltage drop	V_{FM}	80 A, T _J = 25 °C		1.35	V	
Forward slope resistance	r _t	T _{.1} = 150 °C	4.03	mΩ		
Threshold voltage	V _{F(TO)}	1J = 150 C	0.87	V		
Maximum reverse leakage current		T _J = 25 °C	V Dated V	0.1	mA	
Maximum reverse leakage current	I _{RM}	T _J = 150 °C	V _R = Rated V _{RRM}	12	IIIA	

RECOVERY CHARACTERISTICS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •	
Reverse recovery time	t _{rr}	I _F at 80 Apk	480	ns	I _{FM} +	
Reverse recovery current	I _{rr}	25 A/µs	7.1	Α	\	
Reverse recovery charge	Q _{rr}	25 °C	2.1	μC	dir/ Q _{rr}	
Snap factor	S		0.5		I _{RM(REC)}	

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and sto temperature range	rage	T _J , T _{Stg}		- 40 to 150	°C
Maximum thermal resistan junction to case	ce,	R_{thJC}	DC operation	0.35	
Maximum thermal resistan junction to ambient	Maximum thermal resistance, junction to ambient			40	°C/W
Typical thermal resistance case to heatsink	•	R _{thCS}	Mounting surface, smooth and greased	0.2	
Approximate weight				6	g
Approximate weight				0.21	OZ.
Mounting torque	minimum			6 (5)	kgf · cm
	maximum			12 (10)	(lbf · in)
Marking device			Case style TO 247AC (IEDEC)	80EPF10	
warking device			Case style TO-247AC (JEDEC)	80EPF12	

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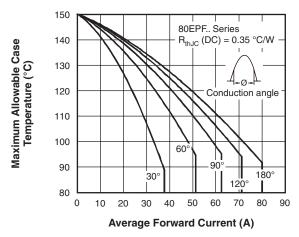


Fig. 1 - Current Rating Characteristics

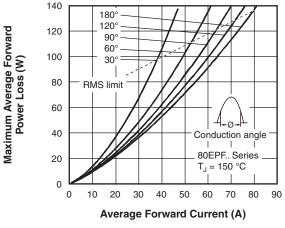


Fig. 4 - Forward Power Loss Characteristics

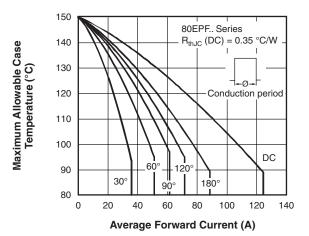


Fig. 2 - Current Rating Characteristics

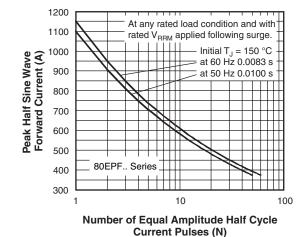


Fig. 5 - Maximum Non-Repetitive Surge Current

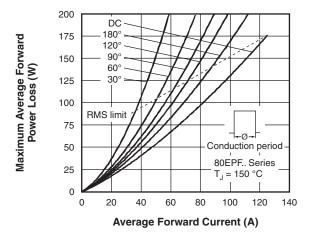


Fig. 3 - Forward Power Loss Characteristics

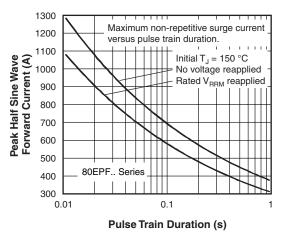


Fig. 6 - Maximum Non-Repetitive Surge Current

80EPF..PbF Soft Recovery Series

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Fast Soft Recovery Rectifier Diode, 80 A



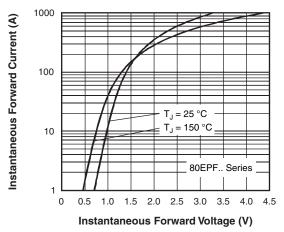


Fig. 7 - Forward Voltage Drop Characteristics

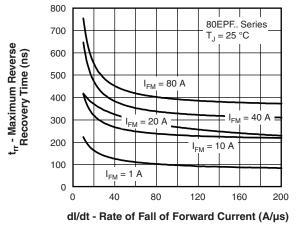


Fig. 8 - Recovery Time Characteristics, T_J = 25 °C

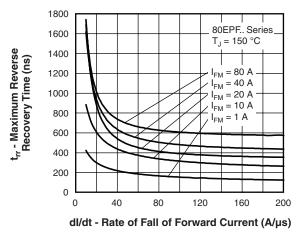


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C

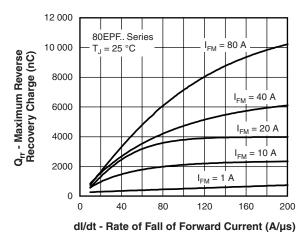


Fig. 10 - Recovery Charge Characteristics, T_{.I} = 25 °C

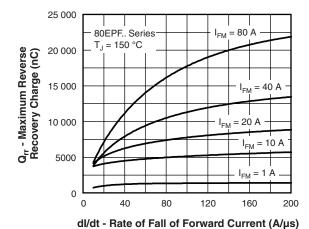


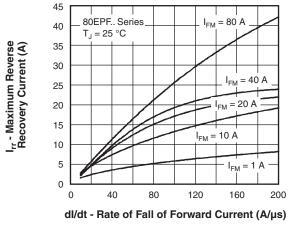
Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

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 $I_{FM} = 80 \text{ A}$ 80EPF.. Series T_J = 150 °C 50 Irr - Maximum Reverse Recovery Current (A) 40 I_{FM} = 10 A 20 10 0 40 80 120 160

dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 12 - Recovery Current Characteristics, $T_J = 25$ °C

Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

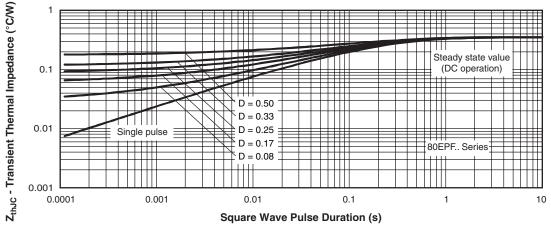


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

80EPF..PbF Soft Recovery Series

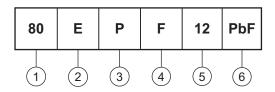
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Fast Soft Recovery Rectifier Diode, 80 A



ORDERING INFORMATION TABLE

Device code



1 - Current rating (80 = 80 A)

2 - Circuit configuration:

E = Single diode

3 - Package:

P = TO-247AC

4 - Type of silicon:

F = Fast diode

5 - Voltage code x 100 = V_{RRM}

10 = 1000 V

12 = 1200 V

- • None = Standard production

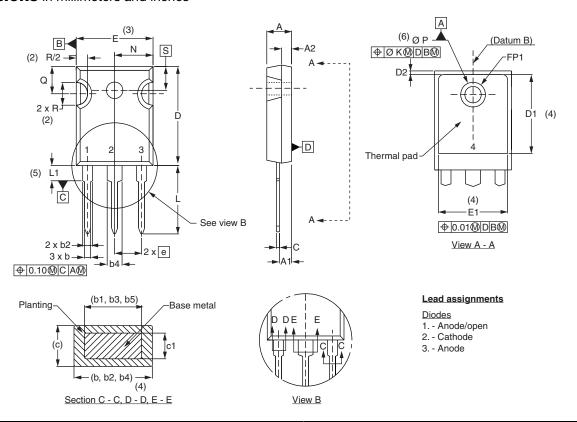
• PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95223				
Part marking information	http://www.vishay.com/doc?95226			



Vishay Semiconductors

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.37	0.065	0.094	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.86	0.015	0.034	
c1	0.38	0.76	0.015	0.030	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
Е	15.29	15.87	0.602	0.625	3
E1	13.72	=.	0.540	-	
е	5.46	BSC	0.215	BSC	
FK	2.54		0.0	10	
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
N	7.62	BSC	0.3		
ΦР	3.56	3.66	0.14	0.144	
ФР1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	1.78	0.216	
S	5.51	BSC	0.217 BSC		

Notes

- $^{(1)}$ Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC outline TO-247 with exception of dimension c

Legal Disclaimer Notice



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